2SD1640

Silicon NPN epitaxial planar type darlington

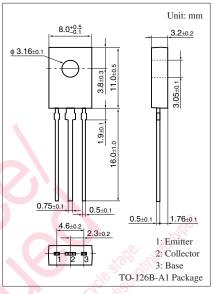
For low-frequency output amplification

Features

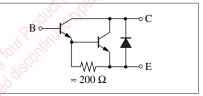
- \bullet High forward current transfer ratio h_{FE}
- \bullet Large peak collector current I_{CP}
- \bullet High collector-emitter voltage (Base open) $V_{\mbox{CEO}}$

Absolute Maximum Ratings $T_a = 25^{\circ}C$

Parameter	Symbol	Rating	Unit	
Collector-base voltage (Emitter open)	V _{CBO}	120	V	
Collector-emitter voltage (Base open)	V _{CEO}	100	V	
Emitter-base voltage (Collector open)	V _{EBO}	5	V	
Collector current	I _C	2	Α	
Peak collector current	I _{CP}	3	A	
Collector power dissipation	P _C	1.2	W	
Junction temperature	Tj	150	°C	
Storage temperature	T _{stg}	-55 to +150	°C	



Internal Connection



Electrical Characteristics $T_a = 25^{\circ}C \pm 3^{\circ}C$

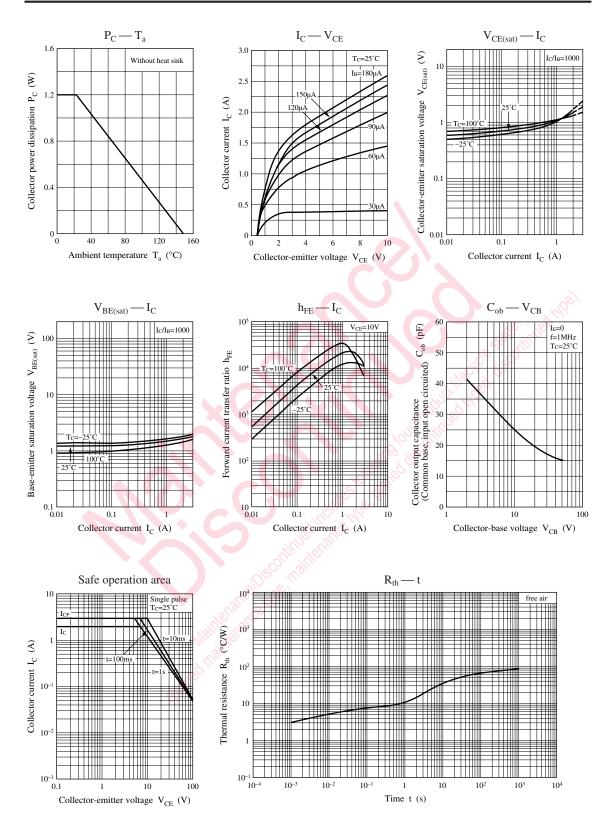
Parameter	Symbol	Conditions	Min	Тур	Max	Unit
Collector-base voltage (Emitter open)	V _{CBO}	$I_{\rm C} = 100 \ \mu A, I_{\rm E} = 0$	120			V
Collector-emitter voltage (Base open)	V _{CEO}	$I_{\rm C} = 1 \text{ mA}, I_{\rm B} = 0$	100			V
Emitter-base voltage (Collector open)	V _{EBO}	$I_{\rm E} = 100 \ \mu A, \ I_{\rm C} = 0$	5			V
Collector-base cutoff current (Emitter open)	I _{CBO}	$V_{CB} = 25 \text{ V}, I_E = 0$			0.1	μΑ
Emitter-base cutoff current (Collector open)	I _{EBO}	$V_{EB} = 4 V, I_C = 0$			1	μΑ
Forward current transfer ratio *1, 2	h _{FE}	$V_{CE} = 10 \text{ V}, I_C = 1 \text{ A}$	4 0 0 0		40 000	
Collector-emitter saturation voltage *1	V _{CE(sat)}	$I_{\rm C} = 1.0 \text{ A}, I_{\rm B} = 1.0 \text{ mA}$			1.5	V
Base-emitter saturation voltage *1	V _{BE(sat)}	$I_{\rm C} = 1.0 \text{ A}, I_{\rm B} = 1.0 \text{ mA}$			2.0	V

Note) 1. Measuring methods are based on JAPANESE INDUSTRIAL STANDARD JIS C 7030 measuring methods for transistors.

2. *1: Pulse measurement *2: Rank classification

Rank	Q	R	S						
\mathbf{h}_{FE}	4000 to 10000	8000 to 20000	16000 to 40000						

Panasonic



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